

PRODUCTS Semiconductor IC

BDE1250G

TYPE

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STRUCTURE

Silicon Monolithic Integrated Circuit

**TYPE** 

**BDE1250G** 

**PRODUCT** 

Thermostat Temperature Sensor

**FEATURES** 

- 1) Highly accurate thermostat ( ±4.0°C )
- 2) Thermostat sensing temperature 125°C
- 3) Open drain output
- 4) Hysteresis temperature ( TYP. 10°C )
- 5) Low supply current ( TYP. 16.0uA )
- 6) Small package ( TYP. 2.90mm × 2.80mm × 1.25mm )

# ■ ABSOLUTE MAXIMUM RATINGS ( Ta = 25°C )

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V <sub>DD</sub>	-0.3 to 7.0*1	V
Input Voltage ( CTRL )	V <sub>IN</sub>	-0.3 to V <sub>DD</sub> +0.3	V
Input Current ( CTRL )	I <sub>IN</sub>	-1.0, +0.1	mA
OS terminal Voltage	V <sub>os</sub>	-0.3 to 7.0	V
OS terminal Current	I <sub>os</sub>	5.0	mA
Power dissipation	Pd	540* <sup>2</sup>	mW
Storage Temperature Range	T <sub>stg</sub>	-55 to 150	°C

<sup>\*1.</sup> Not to exceed Pd

#### RECOMMENDED OPERATING CONDITION

PARAMETERS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Power Supply Voltage	VDD	2.9	3.0	5.5	V
Operating Temperature Range	Topr	-30		130	°C

### ·Status of this document

The Japanese version of this document is the formal specification. A customer may use this translation version only for a reference to help reading the formal version. If there are any difference in translation version of this document, formal version takes priority.

#### Application example

ROHM cannot provide adequate confirmation of patents.

• The product described in this specification is designed to be used with ordinary electronic equipment or devices (such as audio-visual equipment, office-automation equipment, communications devices, electrical appliances, and electronic toys).

Should you intend to use this product with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

ROHM assumes no responsibility for use of any circuits described herein, conveys no license under any patent or other right, and makes no representations that the circuits are free from patent infringement.

DESIGN	CHECK	APPROVAL	DATE : <b>Apr/7/2008</b>	SPECIFICATION No. : TSZ02201-BDE1250G-1-2
T. Tamogravo			REV. A	ROHM CO., LTD.

<sup>\*2.</sup> Reduced by 5.40mW for each increase in Ta of 1°C over 25°C (mounted on 70mm × 70mm × 1.6mm Glass-epoxy PCB)



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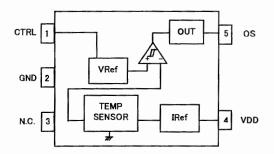
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# BLOCK DIAGRAM



# PIN DESCRIPTION

PIN NO.	PIN NAME	FUNCTION	COMMENT
1	CTRL	Sensing temperature setting	Refer to page 3/4 (TEMPERATURE / OUTPUT FORMAT TABLE) for the sensing temperature setting.
2	GND	GROUND	
3	N.C.	N.C.	
4	VDD	POWER SUPPLY	
5	os	Digital thermostat output	Open Drain type ( Active L ) Use the pull-up resistor more than $10k\Omega$ .

# ■ TEMPERATURE ACCURACY (unless otherwise specified, V<sub>DD</sub> = 3.0V )

	PARAMETER	SYMBOL	LIMIT			UNIT	CONDITIONS	
PARAMETER		STMBOL	MIN.	TYP.	MAX.	ONIT	CONDITIONS	
T	hermostat							
	Sensing Temperature Accuracy	Tacc	-	0	±4.0	လွ	Ta = 125°C	
	Sensing Temperature Hysteresis	Thys	7.5	10.0	12.5	သိ		

# ullet ELECTRICAL CHARACTERISTICS ( unless otherwise specified, $V_{DD}$ = 3.0V, Ta = 25°C )

PARAMETER	SYMBOL		LIMIT		UNIT	CONDITIONS		
FARAMETER		MIN.	TYP.	MAX.	OIVI	CONDITIONS		
Supply Current	ĪDD	-	16.0	20.0	uA	CTRL = L		
OS Output Open Drain	OS Output Open Drain							
OS Leakage Current	ĪL	_	-	1.0	uA	OS : 5.0V		
OS Output Voltage	Vol	-	-	0.4	>	linos = 1.2mA		
CTRL								
Input L Voltage	VIL	GND	_	0.6	V			
Input H Voltage	VIH	2.4	_	VDD	V			

Radiation hardiness is not designed.

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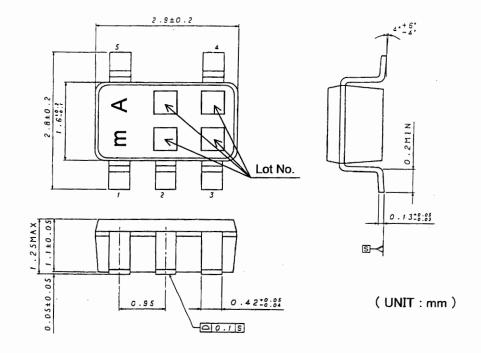
# ● BDE1250G TEMPERATURE / OUTPUT FORMAT TABLE

CTRL INPUT L: Low, O: Open, H: High

	TEMP	SENSING ERATURE	(°C)	OS Ou		
TYPE	CTRL			FORMAT		MARKING
	L	Н	0	TONMAT		
BDE1250G	125	_*3	_*3	Open Drain Active L		mA

<sup>\*3.</sup> Please use CTRL = "L" only. CTRL="H" and "O" are used in manufacturing test mode.

# ● PACKAGE OUTLINES (SSOP5)



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#### CAUTIONS ON USE

#### 1) Absolute Maximum Ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down devices, thus making impossible to identify breaking mode such as a short circuit or an open circuit. If any special mode exceeding the absolute maximum ratings is assumed, consideration should be given to take physical safety measures including the use of fuses, etc.

# 2) GND voltage

Make setting of the potential of the GND terminal so that it will be maintained at the minimum in any operating state.

#### 3) Pin short and mistake fitting

When mounting the IC on the PCB, pay attention to the orientation of the IC. If there is a placement mistake, the IC may be burned up.

## 4) Operation in strong electric field

Be noted that using ICs in the strong electric field can malfunction them.

### 5) Mutual impedance

Use short and wide wiring tracks for the power supply and ground to keep the mutual impedance as small as possible. Use a capacitor to keep ripple to a minimum.

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